Errata TMS320F2810, TMS320F2811, TMS320F2812 DSPs



1 Introduction

This document describes the silicon updates to the functional specifications for the TMS320F2810, TMS320F2811, and TMS320F2812 digital signal processors (DSPs).

The updates are applicable to:

- 128-pin Low-Profile Quad Flatpack (LQFP) [PBK suffix]
- 176-pin LQFP [PGF suffix]
- 179-ball MicroStar BGA[™] [GHH suffix]
- 179-ball lead-free MicroStar BGA [ZHH suffix]
- 179-ball MicroStar BGA[™] [GBB suffix]
- 179-ball lead-free MicroStar BGA[™] [ZAY suffix]

2 Device and Development Tool Support Nomenclature

To designate the stages in the product development cycle, TI assigns prefixes to the part numbers of all [TMS320] DSP devices and support tools. Each TMS320[™] DSP commercial family member has one of three prefixes: TMX, TMP, or TMS (for example, **TMS** 320F2812). Texas Instruments recommends two of three possible prefix designators for its support tools: TMDX and TMDS. These prefixes represent evolutionary stages of product development from engineering prototypes (TMX/TMDX) through fully qualified production devices/ tools (TMS/TMDS).

- TMX Experimental device that is not necessarily representative of the final device's electrical specifications
- **TMP** Final silicon die that conforms to the device's electrical specifications but has not completed quality and reliability verification
- TMS Fully qualified production device

Support tool development evolutionary flow:

- TMDX Development-support product that has not yet completed Texas Instruments internal qualification testing
- TMDS Fully qualified development-support product

TMX and TMP devices and TMDX development-support tools are shipped against the following disclaimer: "Developmental product is intended for internal evaluation purposes."

TMS devices and TMDS development-support tools have been characterized fully, and the quality and reliability of the device have been demonstrated fully. TI's standard warranty applies.

Predictions show that prototype devices (TMX or TMP) have a greater failure rate than the standard production devices. Texas Instruments recommends that these devices not be used in any production system because their expected end-use failure rate still is undefined. Only qualified production devices are to be used.

TI device nomenclature also includes a suffix with the device family name. This suffix indicates the package type (for example, GHH) and temperature range (for example, A).

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3 Device Markings

Figure 3-1 provides an example of the TMS320F281x device markings and defines each of the markings. The device revision can be determined by the symbols marked on the top of the package as shown in Figure 3-1. Some prototype devices may have markings different from those illustrated. Figure 3-2 shows an example of device nomenclature.



Figure 3-1. Example of Device Markings

SILICON REVISION CODE	SILICON REVISION	REVISION ID Address: 0x0883	COMMENTS
Blank (no second letter in prefix)	Indicates Revision 0	0x0000	This silicon revision is available as TMX only.
A	Indicates Revision A	0x0001	This silicon revision is available as TMX only.
В	Indicates Revision B	0x0002	Internal
С	Indicates Revision C	0x0003	TMP/TMX/TMS
D	Indicates Revision D	0x0003	Internal
E	Indicates Revision E	0x0005	Production device (TMS)
F	Indicates Revision F	0x0006	Internal
G	Indicates Revision G	0x0007	Production device (TMS)

Table 3-1. Determining Silicon Revision From Lot Trace Code





Figure 3-2. Example of Device Nomenclature



4 Usage Notes and Known Design Exceptions to Functional Specifications 4.1 Usage Notes

Usage notes highlight and describe particular situations where the device's behavior may not match presumed or documented behavior. This may include behaviors that affect device performance or functional correctness. These usage notes will be incorporated into future documentation updates for the device (such as the device-specific data sheet), and the behaviors they describe will not be altered in future silicon revisions.

Table 4-1 shows which silicon revision(s) are affected by each usage note.

Table 4-1. List of Usage Notes	Table	4-1.	List	of	Usage	Notes
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TITLE		S	ILICON	REVISIO	N(S) AF	FECTED	[1)	
IIILE	0	Α	В	С	D	E	F	G
PIE: Spurious Nested Interrupt After Back-to-Back PIEACK Write and Manual CPU Interrupt Mask Clear	Y	Y	Y	Y	Y	Y	Y	Y

(1) Y = Yes

4.1.1 PIE: Spurious Nested Interrupt After Back-to-Back PIEACK Write and Manual CPU Interrupt Mask Clear Usage Note

Revision(s) Affected: 0, A, B, C, D, E, F and G

Certain code sequences used for nested interrupts allow the CPU and PIE to enter an inconsistent state that can trigger an unwanted interrupt. The conditions required to enter this state are:

- 1. A PIEACK clear is followed immediately by a global interrupt enable (EINT or asm(" CLRC INTM")).
- 2. A nested interrupt clears one or more PIEIER bits for its group.

Whether the unwanted interrupt is triggered depends on the configuration and timing of the other interrupts in the system. This is expected to be a rare or nonexistent event in most applications. If it happens, the unwanted interrupt will be the first one in the nested interrupt's PIE group, and will be triggered after the nested interrupt re-enables CPU interrupts (EINT or asm(" CLRC INTM")).

Workaround: Add a NOP between the PIEACK write and the CPU interrupt enable. Example code is shown below.

<pre>//Bad interrupt nesting code PieCtrlRegs.PIEACK.all = 0xFFFF; EINT;</pre>	//Enable nesting in the PIE //Enable nesting in the CPU
<pre>//Good interrupt nesting code PieCtrlRegs.PIEACK.all = 0xFFFF; asm(" NOP"); EINT;</pre>	//Enable nesting in the PIE //Wait for PIEACK to exit the pipeline //Enable nesting in the CPU



5 Known Design Exceptions to Functional Specifications

Table 5-1 shows which silicon revision(s) are affected by each advisory.

Table	5-1.	List d	of Adv	visories
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Silicon Revision(s) AFFECTED ⁽¹⁾								
TITLE	0	Α	В	С	D	Е	F	G
Memory: Prefetching Beyond Valid Memory	Y	Y	Y	Y	Y	Y	Y	Y
Memory: Program Reads From Flash/ROM Memory	Y	Y	Y	Y	Y	Y	Y	Y
Memory: Flash and OTP Prefetch Buffer Overflow	Y	Y	Y	Y	Y	Y	Y	Y
Memory: Set Device Emulation Register Bits for On-Chip RAM Performance	Y	Y	N/A	N/A	N/A	N/A	N/A	N/A
Memory: OTP Memory	Y	Y	N/A	N/A	N/A	N/A	N/A	N/A
XINTF: XBANK Does Not Properly Extend an Access	Y	Y	Y	Y	Y	Y	Y	Y
XINTF: XREADY Signal is not Sampled Properly When Using Asynchronous Sampling Mode	Y	Y	N/A	N/A	N/A	N/A	N/A	N/A
SCI: Incorrect Operation of SCI in Address Bit Mode	Y	Y	Y	Y	Y	Y	Y	Y
SCI: Bootloader Does Not Clear the ABD Bit After Auto-Baud Lock	Y	Y	Y	Y	Y	Y	Y	Y
SCI: Bootloader Does Not Clear the ABD Bit Before Auto-Baud Lock	Y	Y	Y	Y	Y	Y	Y	Y
eCAN: Abort Acknowledge Bit Not Set	Y	Y	Y	Y	Y	Y	Y	Y
eCAN: CPU Access to the eCAN Registers may Fail if it is in Conflict With an eCAN Access to the eCAN Registers	Y	Y	Y	Y	Y	Y	Y	Y
eCAN: Unexpected Cessation of Transmit Operation	Y	Y	Y	Y	Y	Y	Y	Y
WD: WDFLAG Bit Does Not Work as Intended	Y	Y	Y	Y	Y	Y	Y	Y
WD: A Low Output on GPIOF14 Can Disable the PLL and Watchdog if the Watchdog Fires a Reset	Y	Y	N/A	N/A	N/A	N/A	N/A	N/A
ADC: EOS BUF1/2 Bits in ADCST Corrupted at the End of Conversion of Sequencer 1/2 When INT MOD SEQ1/2 is Enabled	Y	Y	Y	Y	Y	Y	Y	Y
ADC: Reserved Bits in Autosequence Status Register (ADCASEQSR)	Y	Y	Y	Y	Y	Y	Y	Y
ADC: Sequencer Reset While Dual Sequencers Are Running	Y	Y	Y	Y	Y	Y	Y	Y
ADC: Result Register Update Delay	Y	Y	Y	Y	Y	Y	Y	Y
ADC: Device Has Higher Gain Error Than the Design Goal of 1% FSR on All of the B0-B7 Channels	Y	Y	N/A	N/A	N/A	N/A	N/A	N/A
ADC: Device Has Higher Offset Error Than the Design Goal (0.5 to 1%) on Some Channels	Y	Y	N/A	N/A	N/A	N/A	N/A	N/A
ADC: Device Has Higher Non-Linearity Than the Design Goal of 2 LSBs	Y	Y	N/A	N/A	N/A	N/A	N/A	N/A
McBSP: Receive FIFO Read Conflict	Y	Y	Y	Y	Y	Y	Y	Y
McBSP: Read Operations Decrement the McBSP FIFO	Y	Y	Y	Y	Y	Y	Y	Y
SPI: Slave-Mode Operation	Y	Y	Y	Y	Y	Y	Y	Y
Clocking: Logic-High Level for XCLKIN Pin	Y	Y	Y	Y	Y	Y	Y	Y
EV: QEP Circuit	Y	Y	Y	Y	Y	Y	Y	Y
QEP: QEP Inputs in GPIO Asynchronous Mode	Y	Y	Y	Y	Y	Y	Y	Y
DEVICE-ID: Register of the Silicon Same for Revision C and Revision D	N/A	N/A	N/A	N/A	Y	N/A	N/A	N/A
PLL: PLL x4 and x8 Multiplier Ratios	Y	Y	N/A	N/A	N/A	N/A	N/A	N/A
Low-Power Modes - STANDBY Mode	Y	Y	N/A	N/A	N/A	N/A	N/A	N/A

(1) Y = Yes; N/A = Not Applicable



Advisory	Visory Memory: Prefetching Beyond Valid Memory						
Revision(s) Affected	d 0, A, B, C, D, E, F and G						
Details	The C28x CPU prefetches instructions beyond those currently active in its pipeline. If the prefetch occurs past the end of valid memory, then the CPU may receive an invalid opcode.						
Workaround(s)	The prefetch queue is 8x16 words in depth. Therefore, code should not come within 8 words of the end of valid memory. This restriction applies to all memory regions and all memory types (Flash/ROM, OTP, SARAM, XINTF) on the device. Prefetching across the boundary between two valid memory blocks is fine.						
	Example 1: M1 ends at address 0x7FF and is not followed by another memory block. Code in M1 should be stored no farther than address 0x7F7. Addresses 0x7F8–0x7FF should not be used for code.						
	Example 2: M0 ends at address 0x3FF and valid memory (M1) follows it. Code in M0 can be stored up to and including address 0x3FF. Code can also cross into M1 up to and including address 0x7F7.						
Advisory	Memory: Program Reads From Flash/ROM Memory						
Revision(s) Affected	d 0, A, B, C, D, E, F and G						
Details	When an interrupt occurs while program code is executing instructions from the address range 0x3F7FF0 through 0x3F7FF7, it is possible that subsequent data reads from the Flash/ROM will return all zeros.						
Workaround(s)	Do not place program code within this address range. This range can be used for data variable storage.						

Advisory Memory: Flash and OTP Prefetch Buffer Overflow

Revision(s) Affected 0, A, B, C, D, E, F and G

Details

This advisory applies to code executing from flash or OTP with the flash $\tt prefetch$ buffer enabled.

The flash prefetch buffer may overflow if a SBF or BF instruction is within eight 16-bit words preceding an operation using indirect or direct program-memory addressing. The window for which this can occur is shown below:

Address Offset 0x0000 0x0001	BF LSW (32-bit opcode) BF MSW or SBF (16-bit opcode)
0x0002 0x0003 0x0004 0x0005 0x0006 0x0007 0x0008 0x0009	SBF/BF + 1 word//SBF/BF + 2 words//SBF/BF + 3 words// If an instruction within this windowSBF/BF + 4 words// uses program-memory addressing, itSBF/BF + 5 words// can cause the flash prefetch buffer toSBF/BF + 6 words// overflow.SBF/BF + 7 words//SBF/BF + 8 words//
0x0010	SBF/BF + 9 words

Whether or not an overflow actually occurs depends on the instruction sequence, flash wait states and CPU pipeline stalls. If an overflow occurs, it will result in execution of invalid opcodes. Instructions that use program-memory addressing are MAC/XMAC, DMAC/XMACD, QMACL, IMACL, PREAD/XPREAD and PWRITE/XPWRITE.

Workaround(s)

1. Hand-coded assembly:

Use the SB/B instructions instead of SBF/BF for code targeted to execute from flash or OTP. The SB/B instructions are more efficient in wait-stated memory so a performance improvement may also be seen. In addition, the –flash_prefetch_warn compiler option can be used to issue a warning if the assembly code violates this erratum.

2. Compiler-generated assembly:

Use the compiler switch -me to force the compiler to generate SB/B instructions instead of SBF/BF instructions. In heavily wait stated memory, the SB/B instructions are more efficient than SBF/BF. In SARAM, the SBF/BF instructions are more efficient. Therefore, this switch should be applied as follows:

- Use the compiler switch -me on source code that runs from flash or OTP.
- Do not use the compiler switch -me on source code that runs from SARAM.
- Use -me If a file contains functions that runs from flash as well as functions that run from SARAM.

The -me switch is available in C28x compiler v4.1.4 and later.

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Advisory	Memory: Set Device Emulation Register Bits for On-Chip RAM Performance						
Revision(s) Affected	d 0 and A						
Details	•	mance of on-chip RAM blocks M0/M1/L0/L1/H0, the internal control be enabled. The bits are in the Device Emulation Registers.					
Workaround(s)	All device initialization EALLOW-protected re	n code should include the following register updates. These are egisters.					
	Register Address	Value					
	0x950	0x0300					
	0x951	0x0300					
	0x952	0x0300					
	0x953	0x0300					
	0x954	0x0300					
	Code Example:						
	EALLOW MOVL XAR1, #0x0 MOVL XAR2, #0x0 MOV *XAR1++, A MOV *XAR1++, A MOV *XAR1++, A MOV *XAR1++, A	300 R2 R2 R2 R2 R2					

The Code Composer GEL init files will initialize these for emulation and debug environment. From the next silicon revision onward, this initialization is automatically done upon reset.

Advisory Memory: OTP Memory
Revision(s) Affected 0 and A

EDIS

Details The 1K-word OTP memory is not available.

Workaround(s) This is fixed in the next revision of the silicon.

Details

Advisory XINTF: XBANK Does Not Properly Extend an Access

Revision(s) Affected 0, A, B, C, D, E, F and G

When XTIMCLK is not equal to SYSCLKOUT, the XBANK logic may not properly delay a pending access. This occurs for some combinations of XINTF zone wait states and XBANK delay cycles. There are two cases when this occurs.

Case 1: When XTIMCLK = 1/2 SYSCLKOUT and XCLKOUT = XTIMCLK

A pending access may not be delayed by the XBANK logic if either:

- WLEAD + WACTIVE + WTRAIL <= XBANK[BCYC] or
- RLEAD + RACTIVE + RTRAIL <= XBANK[BCYC]

Where WLEAD, WACTIVE, WTRAIL, RLEAD, RACTIVE, RTRAIL are defined as shown in Table 5-2.

	X2TIMING = 0	X2TIMING = 1
WLEAD	XTIMING x [XWRLEAD]	XTIMING x [XWRLEAD] x 2
WACTIVE	XTIMING x [XWRACTIVE] + 1	XTIMING x [XWRACTIVE] x 2 + 1
WTRAIL	XTIMING x [XWRTRAIL]	XTIMING x [XWRTRAIL] x 2
RLEAD	XTIMING x [XRDLEAD]	XTIMING x [XRDLEAD] x 2
RACTIVE	XTIMING x [XRDACTIVE] + 1	XTIMING x [XRDACTIVE] x 2 + 1
RTRAIL	XTIMING x [XRDTRAIL]	XTIMING x [XRDTRAIL] x 2

Table 5-2. Pending Access Relationship	Table	5-2.	Pending	Access	Relationships
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In Table 5-2, XTIMINGx refers to the XTIMING register for Zone x. When XBANK delay cycles are added between two accesses, Zone x refers to the first zone in the sequence. For example: if XBANK[BANK] = 7, then delay cycles will be added to any access into or out of Zone 7. This means:

- Access to Zone 0 followed by Zone 7: the timing of Zone 0 is critical.
- Access to Zone 1 followed by Zone 7: the timing of Zone 1 is critical.
- Access to Zone 7 followed by Zone 0: the timing of Zone 7 is critical.

Thus, the timing of any zone involved in bank switching must be considered.

Case 2) When XTIMCLK = 1/2 SYSCLKOUT and XCLKOUT = 1/2 XTIMCLK:

A pending access may not be delayed properly by the XBANK logic if XBANK[BCYC] = 4 or XBANK[BCYC] = 6.

Workaround(s) Case 1) If XTIMCLK = 1/2 SYSCLKOUT and XCLKOUT = XTIMCLK, then select:

- XBANK[BCYC] <= WLEAD + WACTIVE + WTRAIL and
- XBANK[BCYC] <= RLEAD + RACTIVE + RTRAIL

When XBANK delay cycles are added between two accesses, the timing restriction applies to the first zone accessed as described earlier. The timing of any zone involved in bank switching must be considered.

Table 5-3 shows examples of valid XBANK[BCYC] selections. This list is not exhaustive.



Advisory

(continued)

XINTF: XBANK Does Not Properly Extend an Access

Table 5-3. Examples of Valid XBANK Selections								
XWRLEAD XRDLEAD	WRACTIVE XRDACTIVE	XWRTRAIL XRDTRAIL	X2TIMING	WLEAD + WACTIVE + WTRAIL	Choose XBANK[BCYC]			
1	2	1	0	5	< 5			
1	3	1	0	6	< 6			
2	3	1	0	7	< 7			
1	0	1	1	3	< 3			
1	1	0	1	5	< 5			
1	1	1	1	7	< 7			

Case 2: If XTIMCLK = 1/2 SYSCLKOUT and XCLKOUT = 1/2 XTIMCLK, then select:

- XBANK[BCYC] != 4 and
- XBANK[BCYC] != 6

Advisory XINTF: XREADY Signal is not Sampled Properly When Using Asynchronous Sampling Mode

Revision(s) Affected 0 and A

DetailsIn case of asynchronous ready mode, if the XREADY signal is high within the Lead
period, then access will complete in the number of cycles programmed in LEAD + ACTIVE
+ TRAIL counters even if XREADY goes low before the start of the ACTIVE period. In this
case, XREADY is not being used properly to extend the access.

Workaround(s)

Try one of the following possible workarounds:

- Ensure that the XREADY signal is not low at the start of an access when using asynchronous sampling mode. If the XINTF sees the XREADY signal low from the start of an access, then the ACTIVE period will be extended as desired.
- Use the XTIMING register wait-state values to extend the access such that timings are met without using XREADY.
- Use the synchronous XREADY sampling mode. This problem is not observed in synchronous mode.

This issue is fixed in the next revision of the silicon.

Advisory SCI: Incorrect Operation of SCI in Address Bit Mode

Revision(s) Affected 0, A, B, C, D, E, F and G

Details The SCI does not look for the STOP bit after the ADDR bit. Instead, the SCI starts looking for the start bit beginning on sub-sample 6 of the ADDR bit. Slow rise time from the ADDR bit to the STOP bit can cause a false START bit to occur since the 4th sub-sample for the start bit may be sensed low.

Expected Operation:



Erroneous Operation:





Workaround(s) Program the baud rate of the SCI to be slightly slower than the actual. This will cause the 4th sub-sample of the false START bit to be delayed in time, and therefore occur more towards the middle of the STOP bit (away from the signal transition region). The amount of baud-slowing needed depends on the rise time of the signal in the system. Alternatively, the IDLE mode of the SCI module may be used, if applicable.



Advisory	SCI: Bootloader Does Not Clear the ABD Bit After Auto-Baud Lock				
Revision(s) Affected 0, A, B, C, D, E, F and G					
Details	The SCI ROM bootloader code does not clear the auto-baud detect (ABD) bit in the SCIFFCT register after the auto-baud process completes. If the SCI-A port is used after the bootloader is executed, transmit interrupts (SCITXINTA) will not be able to occur, nor will the auto-baud lock feature of SCI-A work correctly.				
Workaround(s)	If the SCI bootloader has been executed, the user's application code should clear the ABD bit by writing a 1 to ABD CLR (bit 14) in the SCIFFCT register before enabling the SCITXINTA interrupt, and before using the auto-baud feature.				
Advisory	SCI: Bootloader Does Not Clear the ABD Bit Before Auto-Baud Lock				
Revision(s) Affecte	d 0, A, B, C, D, E, F and G				
Details	The SCI ROM bootloader code does not correctly clear the Auto-Baud Detect (ABD) bit in the SCIFFCT register before the auto-baud process begins. The bootloader code fragment is shown below:				
	<pre>// Prepare for autobaud detection // Set the CDC bit to enable autobaud detection // and clear the ABD bit SCIARegs.SCIFFCT.all = 0x2000;</pre>				
	The comments incorrectly state that the ABD bit is cleared. The ABD bit is cleared by writing a 1 to the ABD_CLR bit (bit 14) of the SCIFFCT register. This situation does not hinder operation from power up or reset because the ABD bit is cleared by default after reset. If, however, the bootloader is invoked a second time from software, then the ABD bit will not be cleared and autobaud lock will not occur properly.				
Workaround(s)	If the bootloader is going to be re-invoked by software, the user's code must first clear the ABD bit before calling the bootloader. To do this, write a 1 to the ABD CLR bit (bit 14) in the SCIFFCT register.				

Advisory	eCAN: Abort Acknowledge Bit Not Set							
Revision(s) Affected	1 0, A, B, C, D, E, F and G							
Details	After setting a transmission request reset (TRR) register bit to abort a message, there are some rare instances where the TRRn and TRSn bits will clear without setting the abort acknowledge (AAn) bit. The transmission itself is correctly aborted, but no interrupt is asserted and there is no indication of a pending operation.							
	 In order for this rare condition to occur, all of the following conditions must happen: The previous message was not successful, either because of lost arbitration or because no node on the bus was able to acknowledge it or because an error frame resulted from the transmission. The previous message need not be from the same mailbox in which a transmit abort is currently being attempted. The TRRn bit of the mailbox should be set in a CPU cycle immediately following the cycle in which the TRSn bit was set. The TRSn bit remaining set due to incompletion of transmission satisfies this condition as well—that is, the TRSn bit could have been set in the past, but the transmission remains incomplete. The TRRn bit must be set in the exact SYSCLKOUT cycle where the CAN module is in idle state for one cycle. The CAN module is said to be in idle state when it is not in the process of receiving/transmitting data. If these conditions occur, then the TRRn and TRSn bits for the mailbox will clear t_{clr} SYSCLKOUT cycles after the TRR bit is set where: 							
	The TAn and AAn bits will not be set if this condition occurs. Normally, either the TA or AA							
	bit sets after the TRR bit goes to zero.							
Workaround(s)	When this problem occurs, the TRRn and TRSn bits will clear within t_{clr} SYSCLKOUT cycles. To check for this condition, first disable the interrupts. Check the TRRn bit t_{clr} SYSCLKOUT cycles after setting the TRRn bit to make sure it is still set. A set TRRn bit indicates that the problem did not occur.							
	If the TRRn bit is cleared, it could be because of the normal end of a message and the corresponding TAn or AAn bit is set. Check both the TAn and AAn bits. If either of the bits is set, then the problem did not occur. If they are both zero, then the problem did occur. Handle the condition like the interrupt service routine would except that the AAn bit does not need clearing now.							
	If the TAn or AAn bit is set, then the normal interrupt routine will happen when the interrupt is re-enabled.							



Advisory eCAN: CPU Access to the eCAN Registers may Fail if it is in Conflict With an eCAN Access to the eCAN Registers

Revision(s) Affected 0, A, B, C, D, E, F and G

Details

If contention exists between the CPU and the eCAN controller for access to certain eCAN register areas, a CPU read may erroneously read all zeros (0x00000000), and a CPU write may erroneously fail to execute. Specifically:

- **Case 1:** If the CPU reads the eCAN mailbox RAM area (MSGID, MSGCTRL, MDL, or MDH registers) at the same time that the eCAN controller is accessing (reading or writing) the LAM/MOTO/MOTS register area, the CPU may erroneously read all zeros (0x00000000).
- **Case 2:** If the CPU writes to the eCAN mailbox RAM area (MSGID, MSGCTRL, MDL, or MDH register) at the same time that the eCAN controller is accessing (reading or writing) the LAM/MOTO/MOTS register area, the CPU write may fail to execute.
- **Case 3:** If the CPU reads the LAM/MOTO/MOTS register area at the same time that the eCAN controller is accessing (reading or writing) the eCAN mailbox RAM area (MSGID, MSGCTRL, MDL, or MDH registers), the CPU may erroneously read all zeros (0x00000000).
- Case 4: If the CPU writes to the LAM/MOTO/MOTS register area at the same time that the eCAN controller is accessing (reading or writing) the eCAN mailbox RAM area (MSGID, MSGCTRL, MDL, or MDH registers), the CPU write may fail to execute.

Workaround(s) Workarounds for each of the four cases are as follows:

- **Case 1:** For all CPU reads from the eCAN mailbox RAM area, check to see if the read returns all zeros. If so, the CPU should perform a second read. If the second read returns zero as well, then the data is correctly zero. If the second read returns a non-zero value, then the second data is the correct value. Note that interrupts must be disabled during the consecutive CPU reads. See NOTE 5.
- **Case 2:** For all CPU writes to the eCAN mailbox RAM area, the CPU should write the data twice. Note that interrupts must be disabled during the consecutive CPU writes. See NOTE 5.
- **Case 3:** For all CPU reads from the LAM/MOTO/MOTS register area, check to see if the read returns all zeros. If so, the CPU should perform a second read. If the second read returns zero as well, then the data is correctly zero. If the second read returns a non-zero value, then the second data is the correct value. Note that interrupts must be disabled during the consecutive CPU reads. See NOTE 5.
- **Case 4:** For all CPU writes to the LAM/MOTO/MOTS register area, the CPU should write the data twice with a minimum of 4 CPU cycles in between the writes. Note that interrupts must be disabled during the consecutive CPU writes. See NOTE 5.



	Note
	 An example of the eCAN controller reading the LAM/MOTO/MOTS register area is a read of the LAMn register to check if a received message passes the acceptance mask filtering criterion. This happens during reception of a frame.
	 An example of the eCAN controller writing to the LAM/MOTO/MOTS register area is a write to the MOTSn register to update the timestamp upon successful transmission of a frame.
	 An example for the eCAN controller attempting to read the mailbox RAM area (MSGID, MSGCTRL, MDL, and MDH registers) is right before transmission.
	 An example for the eCAN controller attempting to write to the mailbox RAM area (MSGID, MSGCTRL, MDL, and MDH registers) is right after reception.
	 A C callable assembly implementation of the workaround can be downloaded from the TI Website.

Advisory eCAN: Unexpected Cessation of Transmit Operation

Revision(s) Affected 0, A, B, C, D, E, F and G

Details In rare instances, the cessation of message transmission from the eCAN module has been observed (while the receive operation continues normally). This anomalous state may occur without any error frames on the bus.

Workaround(s) The Time-out feature (MOTO) of the eCAN module may be employed to detect this condition. When this occurs, set and clear the CCR bit (using the CCE bit for verification) to remove the anomalous condition.

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Advisory	WD: WDFLAG Bit Does Not Work as Intended						
Revision(s) Affected	0, A, B, C, D, E, F and G						
Details	The WDFLAG bit in F281x devices cannot be used to reliably distinguish a watchdog- initiated reset from a power-on (or warm) reset. This is because the device expects the XRS pin to be pulled high (by the external reset circuit) within 4 SYSCLKOUT cycles (8 OSCLK cycles at power up) after the end of the watchdog-initiated reset pulse, which is 512 OSCCLK cycles. Most of the external XRS circuits cannot provide the fast rise time requirement (due to the capacitance); therefore, the WDFLAG bit should not be used in applications.						
Workaround(s)	None. This bit should not be used.						
Advisory	VD: A Low Output on GPIOF14 Can Disable the PLL and Watchdog if the Watchdog ires a Reset						
Revision(s) Affected	0 and A						
Details	 If, during program execution, the XF_XPLLDIS/GPIOF14 signal is changed to either of the following: A general-purpose output and driven low The XF functionality and driven low 						
	and a watchdog reset occurs, then the low output state of the XF_ $\overline{XPLLDIS}$ /GPIOF14 pin will be latched into the $\overline{XPLLDIS}$ signal. The result of this is that the PLL and the reset function of the watchdog will be disabled. The watchdog itself is not disabled.						
Workaround(s)	 One of the following workarounds can be used: Do not toggle XF/GPIOF14 in user code. Instead, use another GPIO signal for status. Set the watchdog to fire an interrupt instead of reset. 						

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Advisory	ADC: EOS BUF1/2 Bits in ADCST Corrupted at the End of Conversion of Sequencer 1/2 When INT MOD SEQ1/2 is Enabled						
Revision(s) Affecte	ed 0, A, B, C, D, E, F and G						
Details	Setting the INT MOD SEQx bit in ADCTRL2 as per the user guide should result in the ADC wrapper generating INT SEQx at the end of every other conversion rather than at the end of every conversion. Also, EOS BUFx will be set at the end of every conversion to track the status of the SEQx in use. However, a conversion on SEQ1 will cause EOS_BUF2 to be set if INT_MOD_SEQ2 is enabled for that sequencer, even if INT_MOD_SEQ1 is not enabled.						
	For example, if INT_MOD_SEQ2 is set, a conversion on SEQ1 will cause the EOS_BUF2 bit to be set incorrectly. This will cause INT SEQ2 to be set incorrectly after the next SEQ2 completion. If EOS_BUF2 is already set (from previous SEQ conversion), a conversion on SEQ1 will cause EOS_BUF2 to be cleared causing the interrupt to be missed. The above relationship is also true for SEQ2 affecting SEQ1. In all cases, the sequencers do work correctly, with the exception that EOS BUFx gets corrupted.						
Workaround(s)	Do not use the INT_MOD_SEQx feature if both SEQ1 and SEQ2 will be used before two completions of sequence have completed on the INT_MOD_SEQ selected sequencer.						
Advisory	ADC: Reserved Bits in Autosequence Status Register (ADCASEQSR)						
Revision(s) Affecte	ed 0, A, B, C, D, E, F and G						
Details	SEQ2 STATE2–0 and SEQ1 STATE3–0 bit fields (bits 6 through 0) are the pointers of SEQ2 and SEQ1, respectively. These bits are reserved for TI testing and should not be used in customer applications.						
Workaround(s)	None						
Advisory	ADC: Sequencer Reset While Dual Sequencers Are Running						
Revision(s) Affecte	ed 0, A, B, C, D, E, F and G						
Details	In the TMS320F2812/TMS320F2811/TMS320F2810 on-chip ADC, there are two sequencers for performing ADC conversions; SEQ1 and SEQ2. If one of the sequencers is reset while the other sequencer is running, it will result in the running sequencer never completing its current sequence. The sequencer busy bit (bit 3/bit 2 in ADCST register) for the sequencer will remain active and an "End-of-sequence (EOS)" interrupt for the running sequencer will never be generated. For example, if SEQ1 is reset while SEQ2 is performing a sequence, then SEQ2 will never complete.						
Workaround(s)	If dual sequencers are enabled, then the software handling the ADC module should make sure that SEQ1 BSY/ SEQ2 BSY bits are not set before performing a reset of either sequencer.						



Advisory	ADC: Result Register Update Delay						
Revision(s) Affecte	d 0, A, B, C, D, E, F and G						
Details	The ADC result status flags INT_SEQ1 and INT_SEQ2 bit fields (bits 0 and 1, respectively) in the ADC_ST_FLG register indicate the availability of new ADC results after conversions and initiation of the ADC interrupts.						
	The update of the ADC result register requires one extra ADC cycle to complete after the status flags INT_SEQ1 and INT_SEQ2 bit(s) are set. The result of reading the result register prior to this extra cycle will result in old data being read (reset value/previous conversion result).						
	If auto-sequencers are enabled with a non-zero value in the MAXCONV register, the last result register update takes an additional ADC cycle from the time the INT_SEQ1 or INT_SEQ2 flag is set.						
Workaround(s)	Delay the read of the ADC result register(s) by at least one ADC clock period. This delay can be implemented by using software delay loops.						
	If the ADC result register(s) are read using the ADC interrupt, rather than polling, the wait period introduced by the ISR (interrupt service routine) could minimize the delay needed in software. This ISR branching delay is generally greater than 8 SYSCLKOUT cycles.						
	The ratio of the ADC clock (ADCCLK) to the CPU clock (SYSCLKOUT) determines the size of the software delay. For example, if ADCCLK = 10 MHz, the software delay should be at least 100 ns.						
	 Timing example to estimate the software delay: Get the HSPCLK prescaler value - HISPCP Get the ADCCLK prescaler value - ADCCLKPS Get the CPS (ADCCTRL1[7]) value - CPS Software wait-period in CPU cycles (SYSCLKOUT) before the ADC result register read is defined as: 						

```
Software wait = (HISPCP *2) * (ADCCLKPS * 2) * (CPS +1) cycles
If HISPCP or ADCCLKPS is 0, then the respective terms should be (HISPCP +1)
or (ADCCLKPS+1)
```

Details

Advisory ADC: Device Has Higher Gain Error Than the Design Goal of 1% FSR on All of the B0–B7 Channels

Revision(s) Affected 0 and A

The device has a higher gain error than the design goal of 1% FSR on all of the B0–B7 channels. The gain error varies across channels A0–A7 and B0–B7.

Based on the current data obtained on B group channels, all B group channels show a uniform gain error as high as 2 to 3%.

Workaround(s) The channel-to-channel gain error data across channels are listed in Table 5-4. This should help in calibrating in software or hardware. This was fixed in Revision B silicon.

 Table 5-4. Channel-to-Channel Offset Error Data Across Channels (176-Pin PGF)

ADC CHANNELS	A0	A1	A2	A3	A4	A5	A6	A7	В0	B1	B2	В3	B4	В5	В6	B7
Gain Error in %	0.20	0.18	0.52	0.53	0.53	0.55	0.54	0.54	2.92	2.92	2.92	2.93	2.93	2.93	2.93	2.97
Offset in LSB Counts	14.80	15.64	4.86	9.82	5.82	_ 14.57	_ 13.98	_ 31.78	20.94	21.98	22.48	23.39	22.39	23.14	23.64	24.91

Note

The data provided are typical values only. These values are obtained from bench characterization at room temperature on a few devices.

TMX samples are not fully screened for all ADC parameters. If there are devices that have worse performance than suggested issues/values, it is recommended that the part be replaced.

Advisory	ADC: Device Has Higher Offset Error Than the Design Goal (0.5 to 1%) on Some Channels				
Revision(s) Affect	ed 0 and A				
Details	Based on the current data obtained on all channels, some channels show an offset error as high as 1%.				
Workaround(s)	The channel-to-channel offset error data across channels are listed in Table 5-4. This should help in calibrating in software or hardware. This was fixed in Revision B silicon.				
	The data provided are typical values only. These values are obtained from bench characterization at room temperature on a few devices.				
	TMX samples are not fully screened for all ADC parameters. If there are devices that have worse performance than suggested issues/values, it is recommended that the part be replaced.				



Advisory	ADC: Device Has Higher Non-Linearity Than the Design Goal of 2 LSBs						
Revision(s) Affected	and A						
Details	Based on the current data obtained on all channels, some channels show non-linearity as high as 12 LSBs in the mid-scale range. That is, the mid-range conversions will be off by about 12 LSB counts.						
Workaround(s)	This issue is corrected in the next revision of the silicon. The following option could be used to correct for INL errors only for the TMX Revision A silicon.						
	The INL issue is across all channels. Use the ADC results only for 9-bit data accuracy on this revision of the silicon and ignore the rest of the bits. This will mitigate the INL effect in the application provided the algorithm can tolerate 9-bit accuracy.						
	Note						
	The data provided are typical values only. These values are obtained from bench characterization at room temperature on a few devices.						
	TMX samples are not fully screened for all ADC parameters. If there are devices that have worse performance than suggested issues/values, it is recommended that the part be replaced.						

Advisory	McBSP: Receive FIFO Read Conflict							
Revision(s) Affected	J 0, A, B, C, D, E, F and G							
Details	The McBSP peripheral operates with or without FIFOs. The receive FIFO has interrupt generation logic that initiates interrupts based on the 5-bit FIFO status bits (12–8) and interrupt level bits (4–0) in the MFFRX register.							
	If the CPU reads the receive FIFO while the McBSP module writes new data into the FIFO, there is a potential conflict. The CPU read will not be stalled and read data will not be valid. The FIFO write gets the priority. The receive FIFO will be updated after every word is received in DRR2/1 registers. The DRR2/1 register update time will primarily depend on the word size and CLKR rate. For example, for 8-bit word, it should be typically 8 times the CLKR cycle time. This conflict will be more pronounced if data transferred on the receive channel is back-to-back with no delays between words.							
Workaround(s)	The receive FIFOs should be read based on receive interrupts and within the next word receive time. To avoid the read conflict, additional checks could be used before initiating receive FIFO read. In most McBSP configurations, the FSR is a receiving sync pulse either active high or low (based on the FSR polarity bit) and will go inactive during word transfer time. These active and inactive phases can be detected by checking the FSR flag bit MCFFST (bit 3) register or checking the status of the FSR pin. See the FSR flag bit description for details.							
Advisory	McBSP: Read Operations Decrement the McBSP FIFO							
Revision(s) Affected	d 0, A, B, C, D, E, F and G							
Details	 A read operation from any of the following locations will cause the McBSP receive FIFO contents to decrement by 1, as if the McBSP DRR1 register had been read: 0x7001 Reserved 0x7401 EV-A T1CNT 0x7C01 Reserved 							
	The actual value read from the location is correct and is not affected by this issue.							
Workaround(s)	 Ensure that the McBSP receive FIFO is empty before performing any read operation from any of these addresses. If McBSP traffic is common in the application and a timer count needs to be monitored, consider using a timer other then EV Timer1. 							



Advisory	SPI: Slave-Mode Operation					
Revision(s) Affected 0, A, B, C, D, E, F and G						
Details	When in slave mode, the SPI does not resynchronize received words based on SPISTE. A spurious SPICLK pulse could therefore throw the data stream out of sync.					
Workaround(s)	If the circuit board is not noisy enough to generate spurious SPICLK pulses, then this is not an issue. If noise is an issue, then the McBSP in SPI-slave mode may be used, since the McBSP resynchronizes on each new word.					
Advisory	Clocking: Logic-High Level for XCLKIN Pin					
Revision(s) Affected	d 0, A, B, C, D, E, F and G					
Details	This advisory is applicable only when an external oscillator is used to clock the device. The X1/XCLKIN pin is referenced to the core power supply (V_{DD}), rather than the 3.3-V I/O supply (V_{DDIO}). Therefore, the logic-high level for the input clock should not exceed V_{DD} . This requirement remains the same for future silicon revisions as well.					
Workaround(s)	A clamping diode may be used to clamp a buffered clock signal to ensure that the logic-high level does not exceed V_{DD} (1.8 V or 1.9 V). Otherwise, 1.8-V oscillators may be used.					

Advisory	EV: QEP Circuit				
Revision(s) Affected	Revision(s) Affected 0, A, B, C, D, E, F and G				
Details	 After a DSP reset, the QEP module fails to detect the first transition that occurs on QEP input pins. (This problem also manifests itself when an external clock is used for the EV timers.) Therefore, if the first transition occurs after a GP timer has been initialized and enabled as the QEP counter (that is, to use QEP as source of clock), the first transition will not be counted by the GP timer. The result is an error of one count in the GP timer out of a total of 1024 counts for a 256-line encoder, or 4096 counts for a 1024-line encoder. However, the issue is not a concern under any of the following conditions: 1. The first transition happens before the GP timer is initialized and enabled as QEP counter. This ensures that all transitions are counted after initialization. 2. After the first index pulse is received and if the index pulse is used to recalibrate the GP timer (through capture interrupt). The recalibration corrects the error in the GP timer; therefore, from the time the first index pulse is received, the QEP counter becomes accurate. 				
Workaround(s)	 Make the first transition happen before the GP timer is initialized and enabled as QEP counter. This is usually the case because typically the rotor shaft is locked to a known position before the GP timer is initialized. Locking the rotor shaft will generate transitions on QEP input pins, unless the rotor shaft is exactly aligned to the known position (which is a rare case). Disturbing the rotor shaft on purpose takes care of the rare case. Use the index pulse of the encoder to recalibrate the GP timer used as QEP counter. The counter has to be forced to count before the application actually uses the QEP. During initialization, configure the internal clock (HSPCLK) to be the counter source. After the first count is done, the counter should be reconfigured for external signals (QEP/TCLKIN) and reset to 0. Now the counter will also count the first edge of the QEP. 				
Advisory	QEP: QEP Inputs in GPIO Asynchronous Mode				
Revision(s) Affected 0, A, B, C, D, E, F and G					
Details	If any of the QEP input pins are configured for GPIO asynchronous input mode via the GPxQSELn registers, the QEP module may not operate properly. For example, QPOSCNT may not reset or latch properly, and pulses on the input pins may be missed. This is because the QEP peripheral assumes the presence of external synchronization to SYSCLKOUT on inputs to the module.				
	For proper operation of the QEP module, input GPIO pins should be configured via the GPxQSELn registers for synchronous input mode (with or without qualification). This is the default state of the GPxQSEL registers at reset. All existing QEP peripheral examples supplied by TI also configure the GPIO inputs for synchronous input mode.				
	The asynchronous mode should not be used for QEP module input pins.				
Workaround(s)	Configure GPIO inputs configured as QEP pins for non-asynchronous mode (any GPxQSELn register option except "11b = Asynchronous").				



Advisory	DEVICE-ID: Register of the Silicon Same for Revision C and Revision D			
Revision(s) Affected D				
Details	The DEVICE-ID register of the revision D silicon contains the same value (0x0003) as that of the revision C silicon.			
Workaround(s)	The next revision (revision E) of the silicon has a DEVICE-ID value of 0x0005.			
Advisory	PLL: PLL x4 and x8 Multiplier Ratios			
Revision(s) Affected 0 and A				
Details	When the PLL multiplier is set to x4 or x8 (by writing 0004 or 0008, respectively, in the PLLCR register), the watchdog is re-enabled and resets the device upon a WD overflow. With noisy board conditions, this problem may be observed with other PLL multipliers as well.			
Workaround(s)	Do not use these multiplier values for these revisions.			
	This is fixed in the next revision of the silicon.			
Advisory	Low-Power Modes – STANDBY Mode			
Revision(s) Affected 0 and A				
Details	When the device is put into STANDBY mode, the watchdog is re-enabled and resets the device upon a WD overflow.			
Workaround(s)	Do not use the STANDBY mode for these revisions.			
	This is fixed in the next revision of the silicon.			



6 Documentation Support

For device-specific data sheets and related documentation, visit the TI web site at: http://www.ti.com.

- For more information regarding the TMS320F281x devices, please see the following publication:
- TMS320F281x Digital Signal Processors Data Manual



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Revision History

C	hanges from July 12, 2019 to September 17, 2020 (from Revision R (July 2019) to Revision S	
(S	September 2020))	Page
•	Figure 3-1 (Examples of Device Markings): Updated figure	2

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